## Topological Hall effect in tetragonal Heusler thin films

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Magnetic materials that host topological spin textures have come to the forefront of condensed matter physics and material science as potential candidates for future spintronic applications. Of these spin textures, skyrmions and antiskyrmions are mesoscale whirling objects with distinct chiral magnetic boundaries and opposite topological charges. Of particular interest is the antiskyrmion, which was theoretically predicted to exist in certain tetragonal materials with acentric crystal structures as, e.g.,  $D_{2d}$ . Recently, the tetragonal Heusler compounds [1] show to host antiskyrmions, in addition to other topological spin textures of interest. Spin chirality in metallic materials with noncoplanar spin structure gives rise to a Berry phase induced topological Hall effect (THE), which can be used to distinguish magnetic textures for device applications.

Here, we present the structural, magnetic, and transport properties in epitaxial thin films of the tetragonal  $Mn_xPtSn$  and  $Mn_2RhSn$  Heusler compounds [2,3]. We tune the Mn content (x) by magnetron sputtering, which allows for microscopic control of the magnetic exchange parameters. Further, we observe topological Hall signatures of two distinct chiral spin textures. With our thin film method, we can access a novel and fundamental understanding of this compound not possible with other methods.

## References:

- A. K. Nayak et al., Nature 548, 561-566 (2017).
- [2] P.Swekis et al., Phys. Rev. Materials 3, 013001(R) (2019).
- [3] P. K. Sivakumar et al., ACS Nano 14, 13463 (2020).

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